MOSFETs Silicon P-Channel MOS (U-MOSVII)

# SSM6J511NU

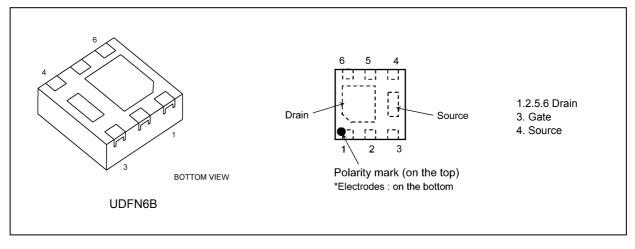
### 1. Applications

Power Management Switches

### 2. Features

- (1) 1.8 V gate drive voltage.
- (2) Low drain-source on-resistance
  - $\begin{array}{l} : {\rm R}_{\rm DS(ON)} = 13.5 \ {\rm m}\Omega \ ({\rm max}) \ (@V_{\rm GS} = -2.5 \ {\rm V}) \\ {\rm R}_{\rm DS(ON)} = 10 \ {\rm m}\Omega \ ({\rm max}) \ (@V_{\rm GS} = -4.5 \ {\rm V}) \end{array}$

# 3. Packaging and Pin Assignment



### 4. Absolute Maximum Ratings (Note) (Unless otherwise specified, T<sub>a</sub> = 25 °C)

	Characteristics			Symbol	Rating	Unit
Drain-source voltage				V <sub>DSS</sub>	-12	V
Gate-source voltage				V <sub>GSS</sub>	±10	
Drain current (DC)			(Note 1)	Ι <sub>D</sub>	-14	A
Drain current (pulsed)			(Note 1), (Note 2)	I <sub>DP</sub>	-40	
Power dissipation	· ·		(Note 3)	PD	1.25	W
Power dissipation		(t ≤ 10 s)	(Note 3)	PD	2.5	W
Channel temperature				T <sub>ch</sub>	150	°C
Storage temperature				T <sub>stg</sub>	-55 to 150	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

- Note 1: Ensure that the channel temperature does not exceed 150 °C.
- Note 2: Pulse width (PW)  $\leq$  10 ms, duty  $\leq$  1 %
- Note 3: Device mounted on a FR4 board. (25.4 mm  $\times$  25.4 mm  $\times$  1.6 mm, Cu pad: 645 mm²)

Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

- Note: The MOSFETs in this device are sensitive to electrostatic discharge. When handling this device, the worktables, operators, soldering irons and other objects should be protected against anti-static discharge.
- Note: The channel-to-ambient thermal resistance, R<sub>th(ch-a)</sub>, and the drain power dissipation, P<sub>D</sub>, vary according to the board material, board area, board thickness and pad area. When using this device, be sure to take heat dissipation fully into account.

### 5. Electrical Characteristics

### 5.1. Static Characteristics (Unless otherwise specified, T<sub>a</sub> = 25 °C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current		I <sub>GSS</sub>	$V_{GS}$ = ±8 V, $V_{DS}$ = 0 V	—	_	±1	μA
Drain cut-off current		I <sub>DSS</sub>	V <sub>DS</sub> = -12 V, V <sub>GS</sub> = 0 V	—		-1	μA
Drain-source breakdown voltage		V <sub>(BR)DSS</sub>	I <sub>D</sub> = -1 mA, V <sub>GS</sub> = 0 V	-12		—	V
Drain-source breakdown voltage	(Note 1)	V <sub>(BR)DSX</sub>	I <sub>D</sub> = -1 mA, V <sub>GS</sub> = 5 V	-7	_	—	V
Gate threshold voltage	(Note 2)	V <sub>th</sub>	V <sub>DS</sub> = -3 V, I <sub>D</sub> = -1 mA	-0.3	_	-1.0	V
Drain-source on-resistance	(Note 3)	R <sub>DS(ON)</sub>	I <sub>D</sub> = -4 A, V <sub>GS</sub> = -8 V	—	6.5	9.1	mΩ
			I <sub>D</sub> = -4 A, V <sub>GS</sub> = -4.5 V	_	7.1	10	
			I <sub>D</sub> = -4 A, V <sub>GS</sub> = -3.6 V	_	7.5	11.5	
			I <sub>D</sub> = -4 A, V <sub>GS</sub> = -2.5 V	_	8.5	13.5	
			I <sub>D</sub> = -4 A, V <sub>GS</sub> = -1.8 V	_	11.0	19.2	
Forward transfer admittance	(Note 3)	Y <sub>fs</sub>	V <sub>DS</sub> = -3 V, I <sub>D</sub> = -2.0 A	_	27	_	S

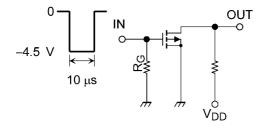
Note 1: If a reverse bias is applied between gate and source, this device enters V<sub>(BR)DSX</sub> mode. Note that the drainsource breakdown voltage is lowered in this mode.

Note 3: Pulse measurement.

# 5.2. Dynamic Characteristics (Unless otherwise specified, $T_a = 25$ °C)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C <sub>iss</sub>	V <sub>DS</sub> = -6 V, V <sub>GS</sub> = 0 V,	_	3350	_	pF
Reverse transfer capacitance	C <sub>rss</sub>	f = 1 MHz	_	570	_	
Output capacitance	C <sub>oss</sub>		—	590	_	
Switching time (turn-on time)	t <sub>on</sub>	V <sub>DD</sub> = -6 V, I <sub>D</sub> = -1.0 A V <sub>GS</sub> = 0 to -4.5 V, R <sub>G</sub> = 6 Ω,	_	50	_	ns
Switching time (turn-off time)	t <sub>off</sub>	$\begin{array}{l} Duty \leq 1 \ \%, V_{IN}: \ t_r, \ t_f < 5 \ ns, \\ Common \ source, \ See \ Chapter \ 5.3. \end{array}$		554		

### 5.3. Switching Time Test Circuit



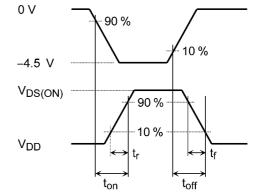


Fig. 5.3.1 Switching Time Test Circuit

Fig. 5.3.2 Input Waveform/Output Waveform

Note 2: Let  $V_{th}$  be the voltage applied between gate and source that causes the drain current (I<sub>D</sub>) to below (-1 mA for this device). Then, for normal switching operation,  $V_{GS(ON)}$  must be higher than  $V_{th}$ , and  $V_{GS(OFF)}$  must be lower than  $V_{th}$ . This relationship can be expressed as:  $V_{GS(OFF)} < V_{th} < V_{GS(ON)}$ . Take this into consideration when using the device.

# 5.4. Gate Charge Characteristics (Unless otherwise specified, $T_a = 25$ °C)

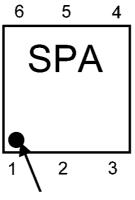
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)		$V_{DD}$ = -6 V, $V_{GS}$ = -4.5 V,	_	47	—	nC
Gate-source charge 1	Q <sub>gs1</sub>	I <sub>D</sub> = -10 A	_	2.7	—	
Gate-drain charge	Q <sub>gd</sub>		_	8.5	_	

# 5.5. Source-Drain Characteristics (Unless otherwise specified, $T_a = 25$ °C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit
Diode forward voltage	(Note 1)	$V_{\text{DSF}}$	I <sub>D</sub> = 4 A, V <sub>GS</sub> = 0 V		0.6	1.0	V

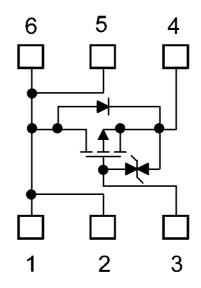
Note 1: Pulse measurement.

#### 6. Marking

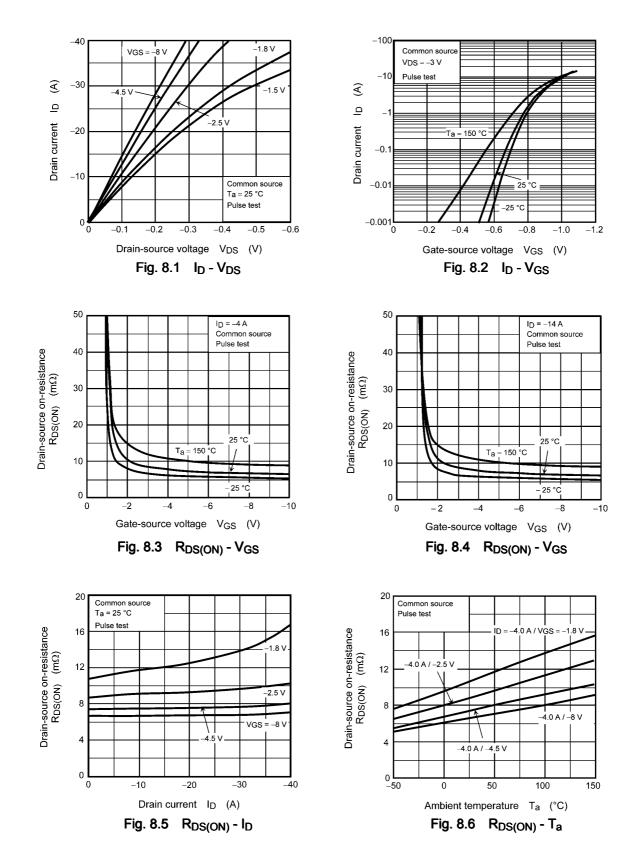


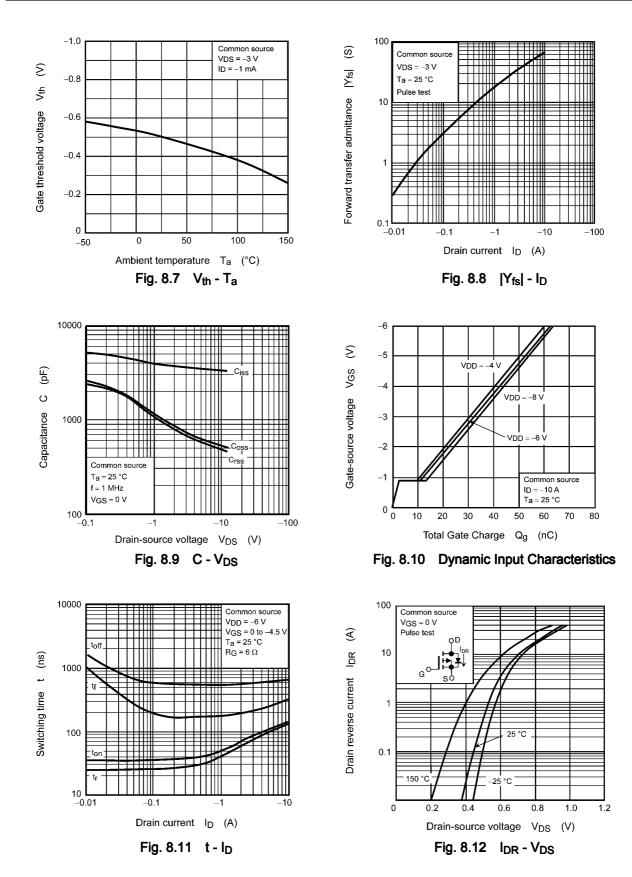
Polarity mark

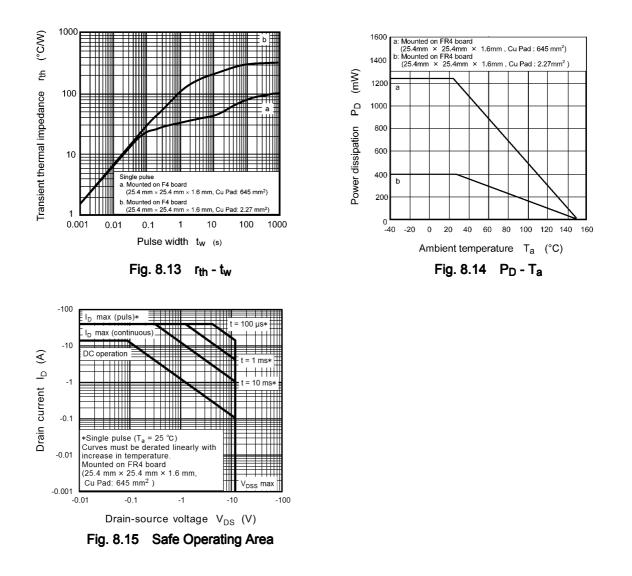
# 7. Internal Equivalent Circuit



# 8. Characteristics Curves (Note)







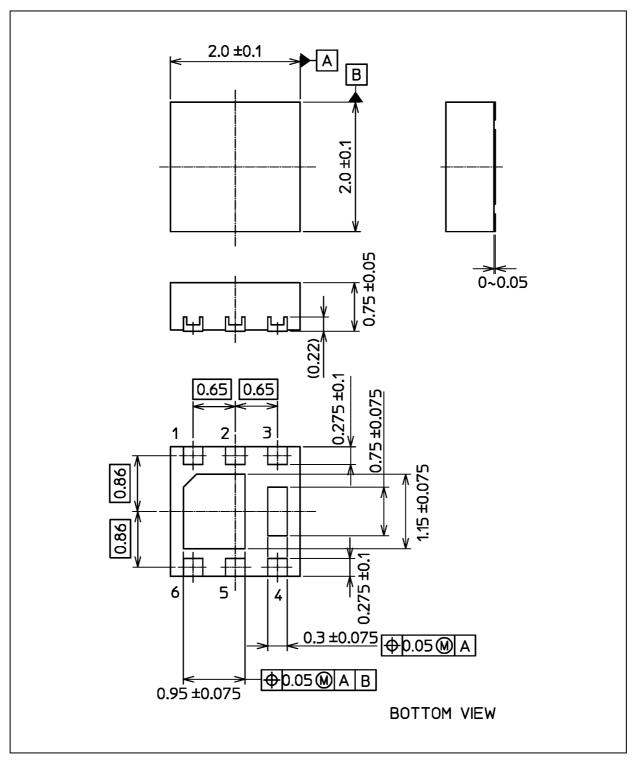
Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.



## Package Dimensions

SSM6J511NU

Unit: mm



#### Weight: 8.5 mg (typ.)

	Package Name(s)
JEDEC: SOT-1220	
Nickname: UDFN6B	

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